

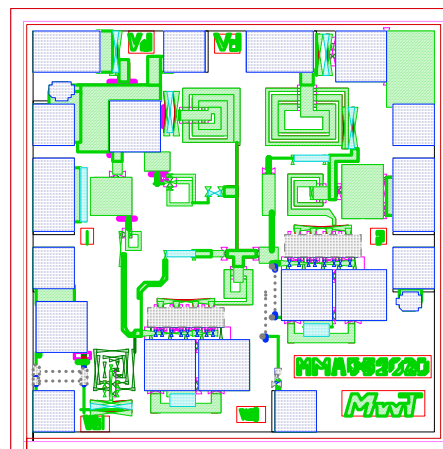
MMA-062020 6 - 22 GHz, 0.1 W Gain Block

Features:

- Frequency Range: 6 – 22 GHz
- P1dB: 18.5 dBm @ Vds = 5 V
- Psat: 19.5 dBm @ Vds = 5 V
- Gain: 14 dB
- Vdd = 3 to 6 V
- Ids = 130 mA
- Input and Output Fully Matched to 50 Ω

Applications:

- Communication systems
- Microwave instrumentations
- ECM



Die size: 920 μm x 920 μm x 50 μm

Description:

The MMA-062020 is a broadband GaAs MMIC general purpose gain block for 20 dBm saturated maximum output power and high gain over full 6 to 22 GHz frequency range. This amplifier was optimally designed for broadband applications requiring flat gain with excellent input and output port matches.

Absolute Maximum Ratings: (Ta = 25 °C)*

SYMBOL	PARAMETERS	UNITS	Min.	Max.
Vd1, Vd2	Drain-Supply Voltage	V		6.5
Vg1	Optional Gate supply Voltage	V	-5	1
Vg2	Optional Gate supply Voltage	V	-10	1
Id1	Drain Supply Current	mA		70
Id2	Drain Supply Current	mA		84
Pin max	RF Input Power	dBm		20
Toper	Operating Temperature	°C		-40 to +85
Tch	Channel Temperature	°C		+150
Tstg	Storage Temperature	°C		-55 to +165
Tmax	Max. Assembly Temp (60 sec max)	°C		+300

*Operation of this device above any one of these parameters may cause permanent damage.

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Electrical Specifications: $V_{ds} = 5\text{ V}$, $I_{ds} = 130\text{ mA}$, $T_a = 25\text{ }^{\circ}\text{C}$, $Z_0 = 50\text{ }\Omega$

Parameter	Units	Typical Data
Frequency Range	GHz	6 - 22
Gain (Typ / Min)	dB	14 / 13.5
Gain Flatness (Typ / Max)	$\pm$ dB	0.8 / 1
Input RL(Typ / Max)	dB	8 / 7
Output RL(Typ / Max)	dB	10 / 8
Output P1dB(Typ / Min)	dBm	18.3 / 18
Output IP3 ⁽¹⁾	dBm	28
Output Psat(Typ / Min)	dBm	19.5 / 19
Operating Current at P1dB (Typ / Max)	mA	120 / 130
Thermal Resistance	$^{\circ}\text{C} / \text{W}$	60

(1) Output IP3 is measured with two tones at output power of 0 dBm / tone separated by 20 MHz.

ESD Caution

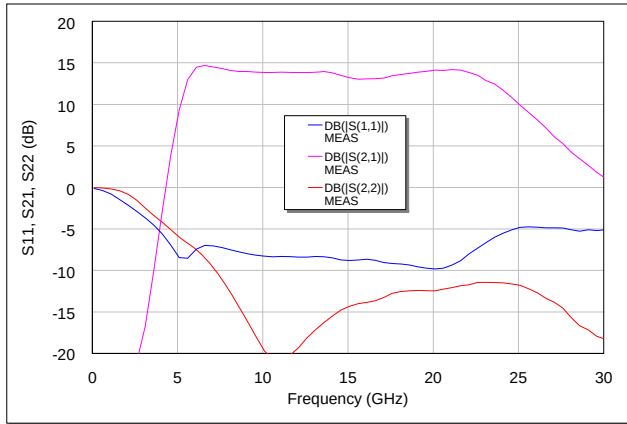


High-performance RF integrated circuits are highly sensitive to electrostatic discharge (ESD) and may contain unprotected inputs and outputs. Handling and assembly should be conducted in an ESD-controlled environment. It is recommended that ESD precautions and protocols are adopted to minimise the risk of electrostatic discharge and protect product integrity.

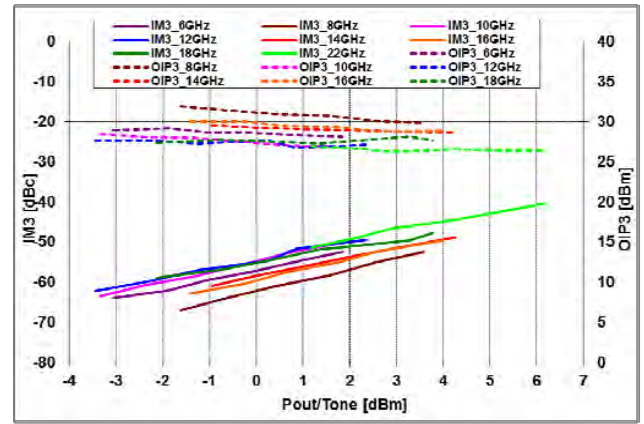
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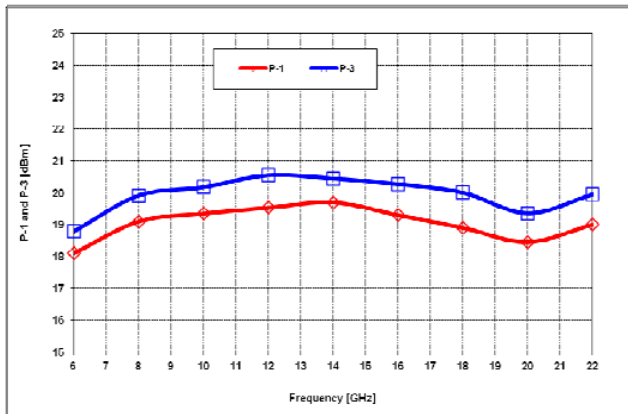
Typical RF Performance: $V_{ds} = 5\text{ V}$, $I_{ds} = 130\text{ mA}$, $Z_0 = 50\ \Omega$, $T_a = 25\text{ }^\circ\text{C}$



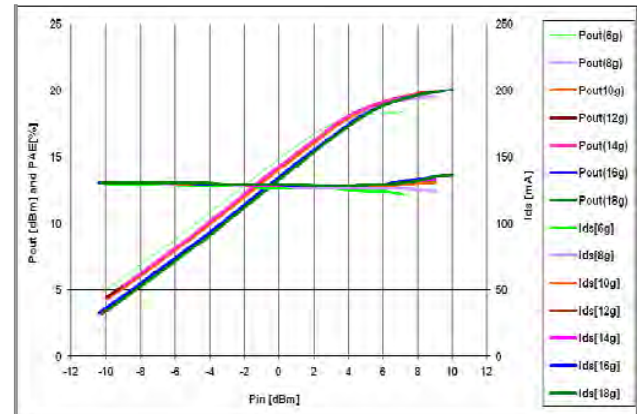
S11 [dB], S21 [dB], and S22 [dB] vs. Frequency



IM3 level [dBc] vs. Output power/tone [dBm]

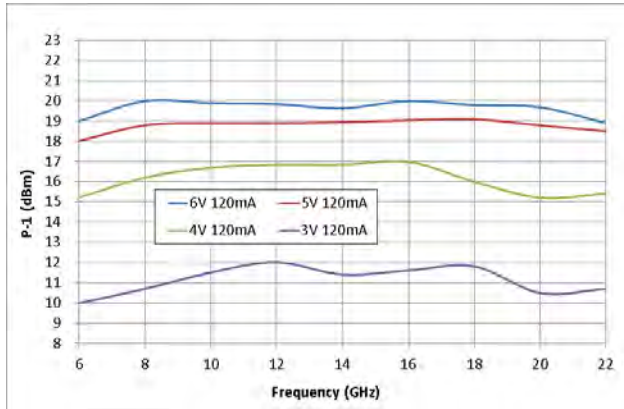


P-1 and Psat vs. Frequency

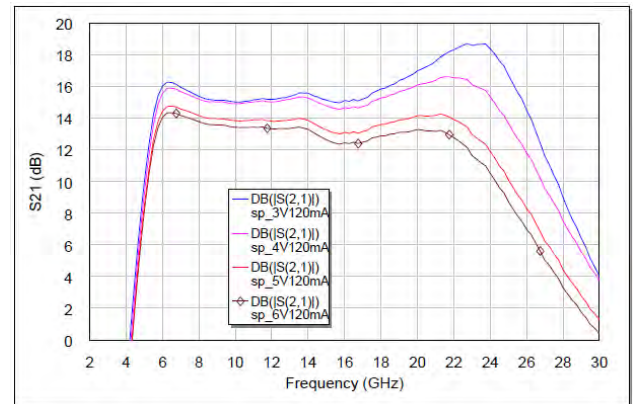


Pout [dBm], Gain [dB], and Ids [mA] vs. Input power [dBm]

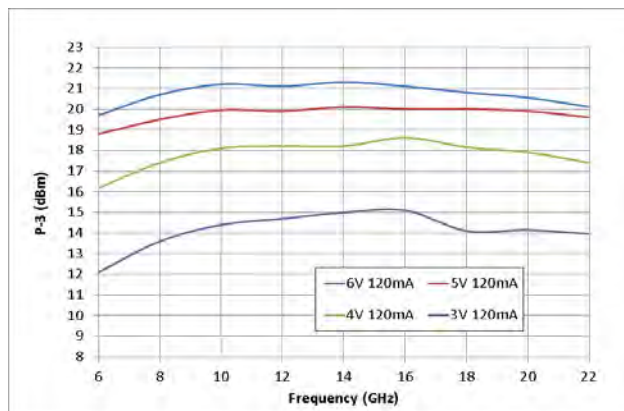
Typical Bias dependent RF Performance:



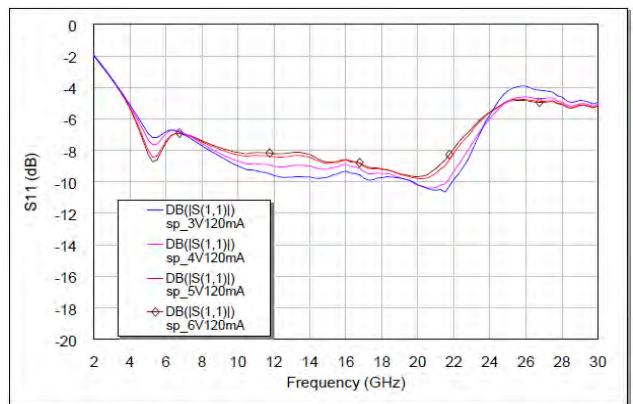
Bias dependent P-1 (dBm) vs. Frequency



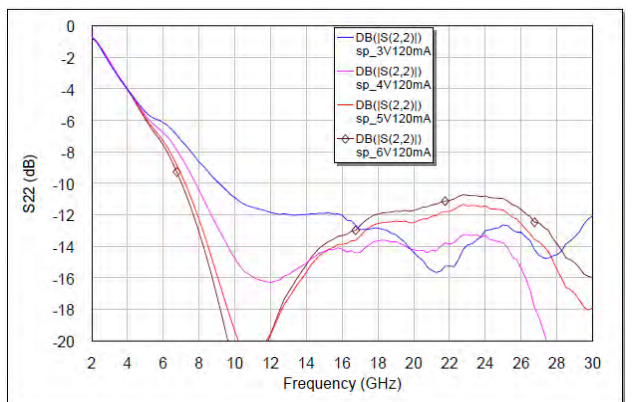
S21 (dB) vs. Voltage



Bias dependent P-3 (dBm) vs. Frequency



S11 (dB) vs. Voltage

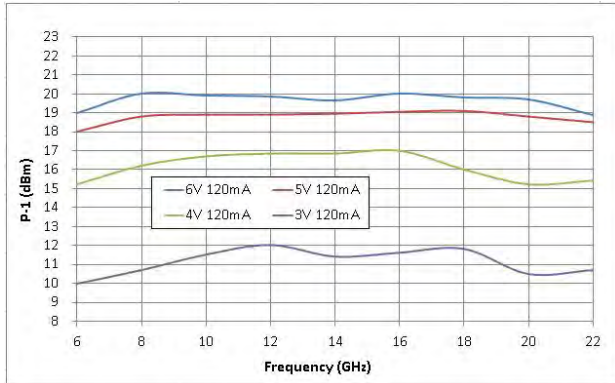


S22 (dB) vs. Voltage

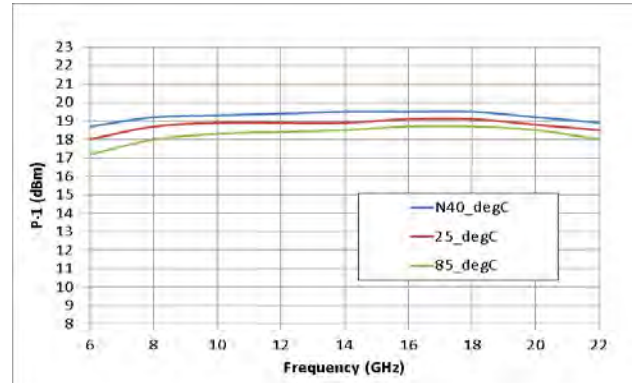
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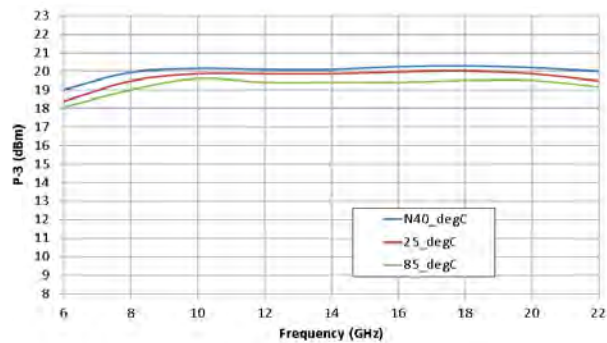
Typical Over Temperature RF Performance: $V_{ds} = 5\text{ V}$, $I_{ds} = 130\text{ mA}$, $Z_0 = 50\ \Omega$, $T_a = 25\text{ }^\circ\text{C}$



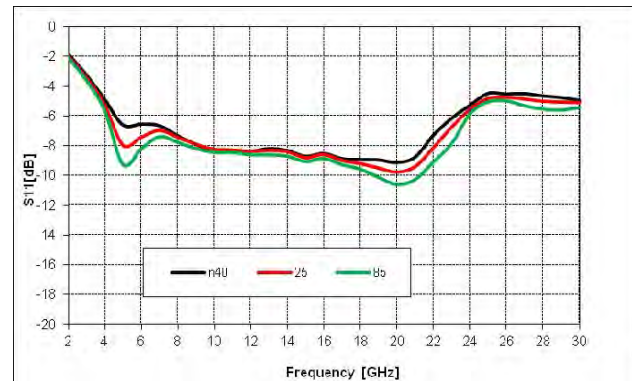
P-1 (dBm) over temperature



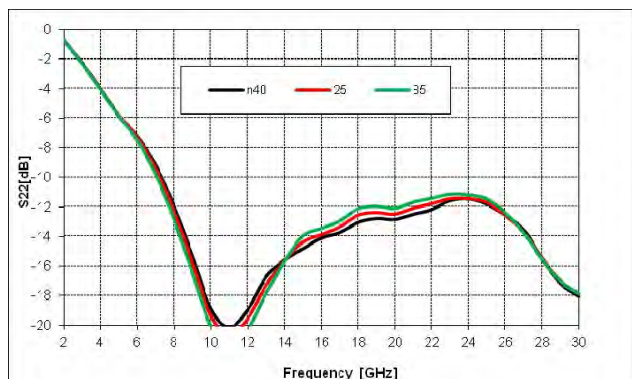
S21 (dB) vs. temperature



P-3 (dBm) over temperature



S11(dB) vs. temperature



S22 (dB) vs. Voltage

Applications

The **MMA-062020** is a GaAs PHEMT amplifier designed for Class-A condition, flat gain performance from 6 GHz to 22 GHz. It is applicable for cascadable gain stage for EW amplifiers, buffer stages, LO drivers, and transmitter amplifiers used in commercial communication systems. This amplifier is provided as a bare die format in a Gel-pak.

Biasing and Operation

The **MMA-062020** is normally biased with a single positive supply voltage connected to both Vd1 and Vd2 pins. The recommended drain supply voltages are 3 to 6 volts. RF input and output ports are DC decoupled internally. Typical DC supply connection with bi-passing capacitors for the **MMA-062020** is shown in following pages.

Optional gate pads (Vg1 and Vg2) are also provided to allow adjustments in gain, RF output power, and DC power dissipation, if necessary. No connection to the gate pads is needed for single drain-bias operation. However, for custom applications, the DC current flowing through the input and/or output gain stage may be adjusted by applying a voltage to the gate bias pad(s) as shown in Figure 5. A negative gate-pad voltage will decrease the drain current. The gate-pad voltage is approximately zero volts during operation with no DC gate supply. Refer to the absolute maximum rating table for allowing DC and thermal conditions.

Assembly Techniques

GaAs MMICs are ESD sensitive. ESD preventive measures must be employed in all aspects of storage, handling, and assembly. MMIC ESD precautions, handling considerations, die attach and bonding methods are critical factors in successful GaAs MMIC performance and reliability.

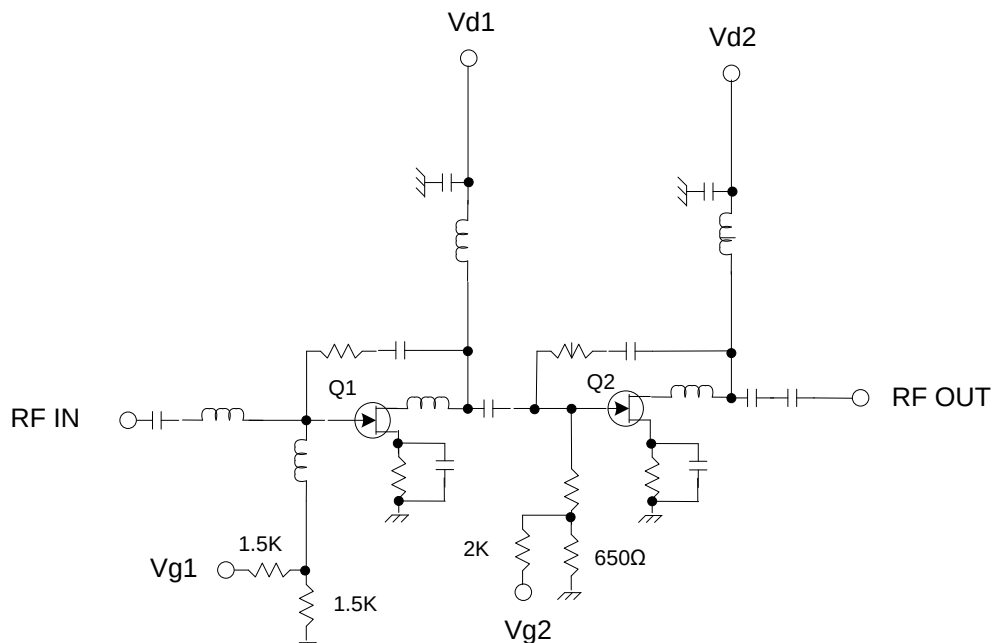


Figure 1 MMA062020 Simplified schematic

The micrograph shows the physical layout of the MMIC. The layout is enclosed in a red rectangular frame. The coordinate system is defined by the following labels and values:

- Horizontal Axis (X):**
 - 0, 165, 365, 570, 920
 - Labels: V_{d1} , GND, V_{d2}
- Vertical Axis (Y):**
 - 0, 535, 920
 - Labels: V_{g1} , RF_OUT, 0
- Input/Output Labels:**
 - RF_IN (top left)
 - RF_OUT (middle right)
- Internal Labels:**
 - Vd1, Vd2, Vg1, Vg2 (small red boxes)
 - R1 (small red box)
 - © 2011 MWT (copyright notice)
 - WMA002020 (part number)

Figure 2. Die outline and bonding pad locations

Application Circuit:

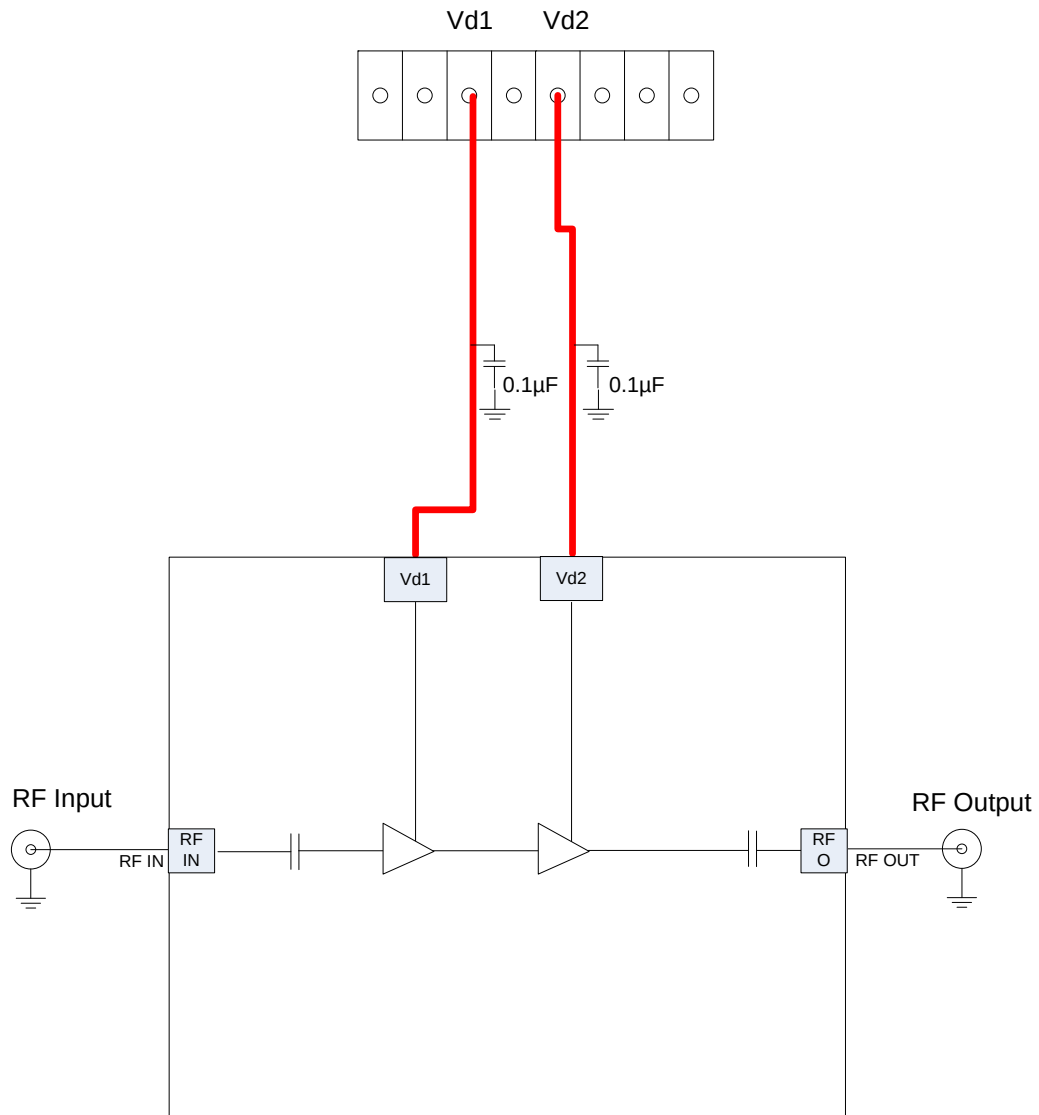


Figure 3 Application for single drain-bias operation

Recommended Assembly:

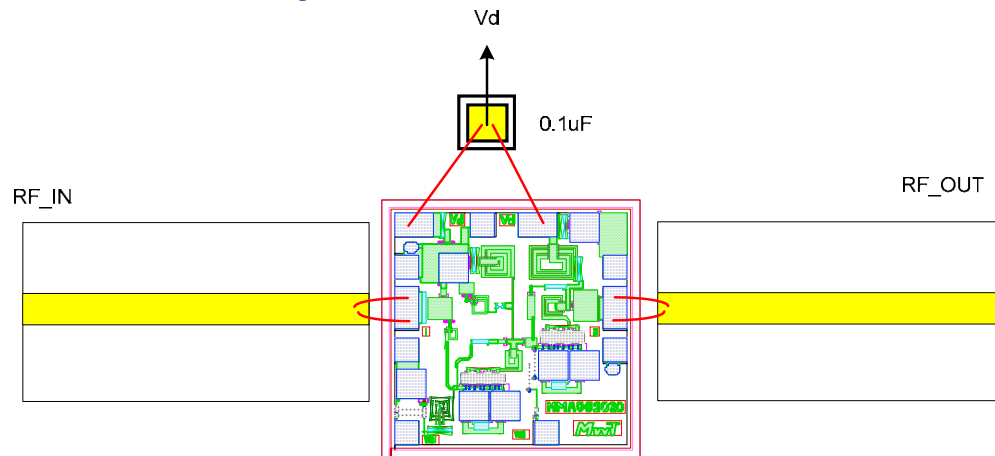


Figure 4 Assembly for single drain-bias operation

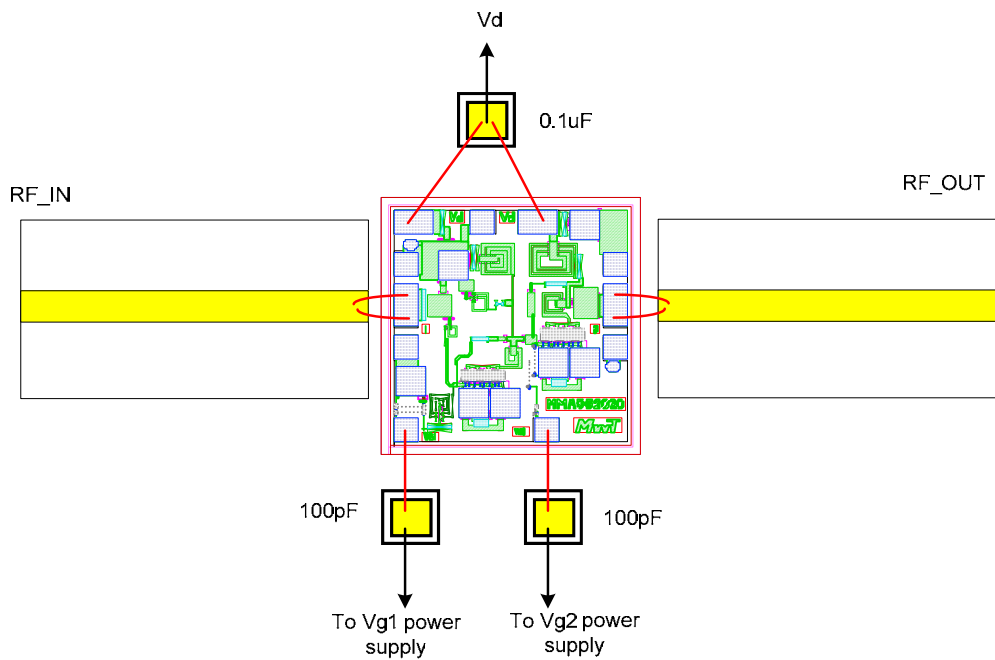
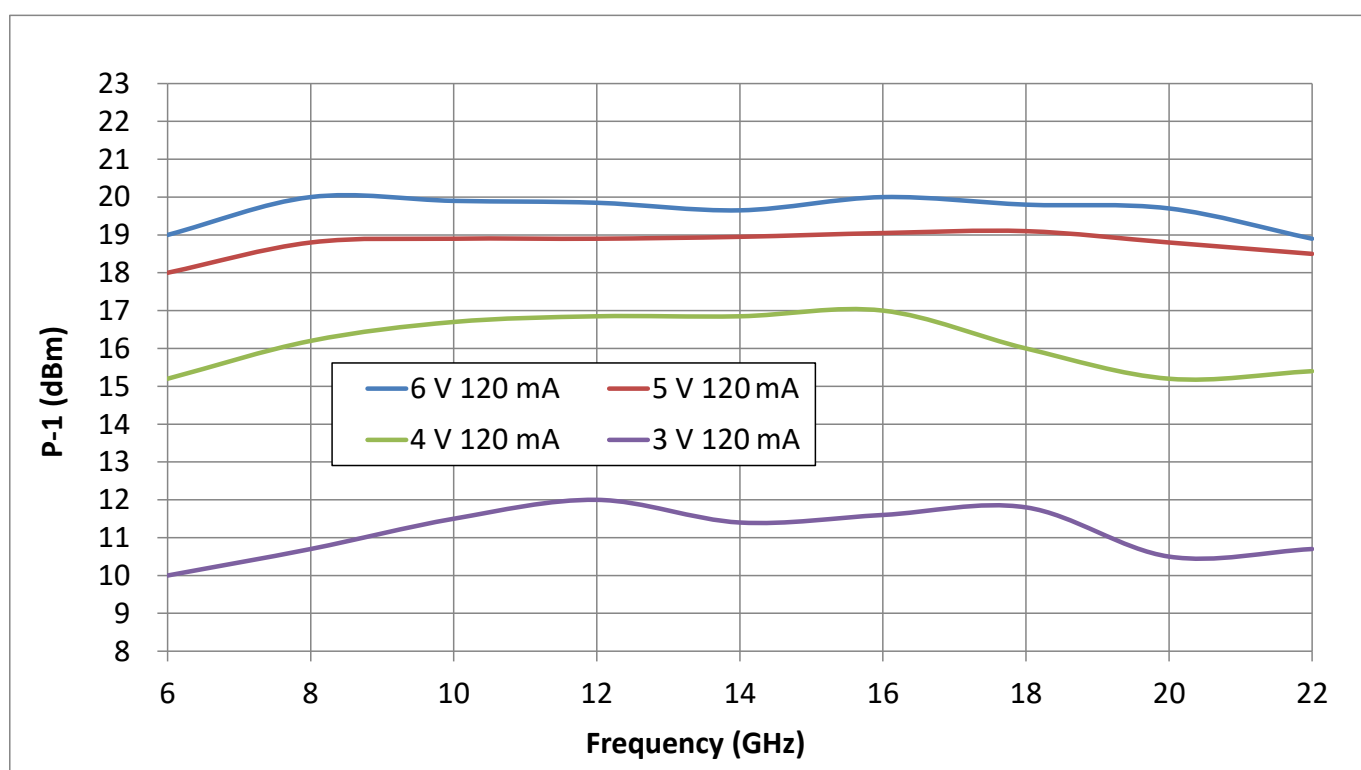


Figure 5 Assembly with gate bias connection

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REACH Compliance



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